NSN 5961-01-043-7071

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-043-7071 **Inclosure Material:** Ceramic **Overall Length:** Between 0.264 inches and 0.274 inches **Overall Diameter:** 0.125 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Thread Size:** 0.125 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector minor **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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